Voltage Detector IC Series

Counter Timer Built-in CMOS Voltage Detector IC

BD45xxx series   BD46xxx series

Pb Free
ROHM Electronic Components

RoHS
Directive Compliance

●General Description

ROHM's BD45xxx and BD46xxx series are highly accurate, low current consumption Voltage Detector ICs. Because the counter timer delay circuit is built into these series, an external capacitor for the delay time setting is unnecessary. The lineup was established with low output types (Nch open drain and CMOS output) and detection voltages range from 2.3V to 4.8V in increments of 0.1V, so that the series may be selected according the application at hand.

●Features

- Counter Timer Built-in
- No delay time setting external capacitor required
- Ultra-low current consumption
- Two output types (Nch open drain and CMOS output)
- Package SSOP5 is similar to SOT-23-5 (JEDEC)

●Key Specifications

|		
■ Detection voltage:	2.3V to 4.8V (Typ.)
	0.1V steps
■ High accuracy detection voltage:	±1.0%
■ Ultra-low current consumption:	0.85µA (Typ.)
■ Operating temperature range:	-40°C to +105°C
■ Three internal, fixed delay time:	50ms
	100ms
	200ms

●Package

SSOP5   ROHM   2.90mm x 2.80mm x 1.25mm

●Applications

Circuits using microcontrollers or logic circuits that require a reset.
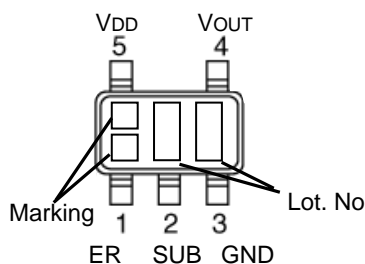
●Typical Application Circuit
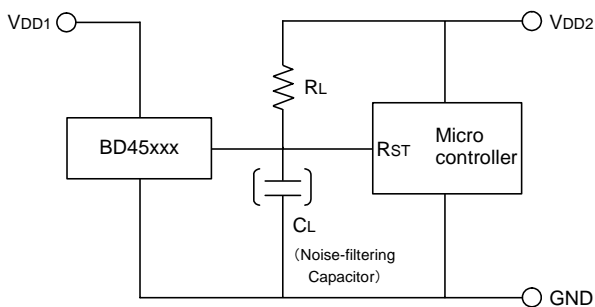
（Open Drain Output Type）
BD45xxx series
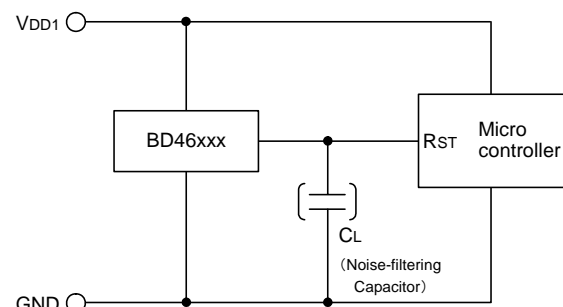
（CMOS Output Type）
BD46xxx series

●Connection Diagram
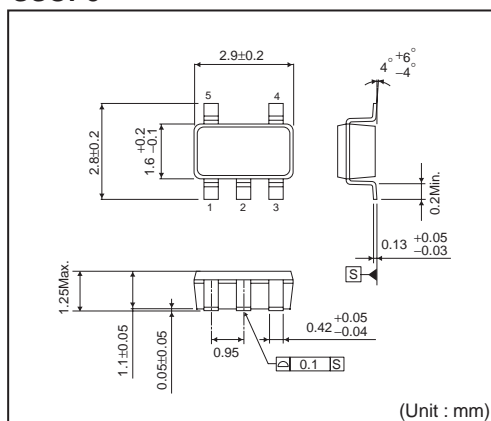
SSOP5

●Pin Descriptions

PIN No.	Symbol	Function
1	ER	Manual Reset
2	SUB	Substrate *
3	GND	GND
4	VOUT	Reset Output
5	VDD	Power Supply Voltage

*Connect the substrate to GND.

○Product structure : Silicon monolithic integrated circuit   ○This product is not designed for protection against radioactive rays

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●Ordering Information

| B | D | x | x | x | x | x | x | – | T | R |

Part Number

Output Type
45 : Open Drain
46 : CMOS

Reset Voltage Value
23 : 2.3V
⇩   0.1V step
48 : 4.8V

Counter Timer Delay Time Settings
5 : 50ms
1 : 100ms
2 : 200ms

Package
G : SSOP5

Packaging and forming specification
TR : Embossed tape and reel

SSOP5

2.9±0.2
4°⁺⁶°₋₄°
2.8±0.2
1.6⁺⁰·²₋₀·₁
0.2Min.
0.13⁺⁰·⁰⁵₋₀·₀₃
S
1.25Max.
1.1±0.05
0.05±0.05
0.95
0.42⁺⁰·⁰⁵₋₀·₀₄
0.1 S

(Unit : mm)

<Tape and Reel information>

Tape	Embossed carrier tape
Quantity	3000pcs
Direction of feed	TR (The direction is the 1pin of product is at the upper right when you hold reel on the left hand and you pull out the tape on the right hand)

1pin

Reel   Direction of feed

＊Order quantity needs to be multiple of the minimum quantity.

●Lineup

Table 1. Open Drain Output Type

Detection Voltage	Counter Timer Delay Time Settings					
	50ms		100ms		200ms	
	Marking	Part Number	Marking	Part Number	Marking	Part Number
4.8V	T0	BD45485	TS	BD45481	UJ	BD45482
4.7V	T1	BD45475	TT	BD45471	UK	BD45472
4.6V	T2	BD45465	TU	BD45461	UL	BD45462
4.5V	T3	BD45455	TV	BD45451	UM	BD45452
4.4V	T4	BD45445	TW	BD45441	UN	BD45442
4.3V	T5	BD45435	TX	BD45431	UP	BD45432
4.2V	T6	BD45425	TY	BD45421	UQ	BD45422
4.1V	T7	BD45415	TZ	BD45411	UR	BD45412
4.0V	T8	BD45405	U0	BD45401	US	BD45402
3.9V	T9	BD45395	U1	BD45391	UT	BD45392
3.8V	TA	BD45385	U2	BD45381	UU	BD45382
3.7V	TB	BD45375	U3	BD45371	UV	BD45372
3.6V	TC	BD45365	U4	BD45361	UW	BD45362
3.5V	TD	BD45355	U5	BD45351	UX	BD45352
3.4V	TE	BD45345	U6	BD45341	UY	BD45342
3.3V	TF	BD45335	U7	BD45331	UZ	BD45332
3.2V	TG	BD45325	U8	BD45321	V0	BD45322
3.1V	TH	BD45315	U9	BD45311	V1	BD45312
3.0V	TJ	BD45305	UA	BD45301	V2	BD45302
2.9V	TK	BD45295	UB	BD45291	V3	BD45292
2.8V	TL	BD45285	UC	BD45281	V4	BD45282
2.7V	TM	BD45275	UD	BD45271	V5	BD45272
2.6V	TN	BD45265	UE	BD45261	V6	BD45262
2.5V	TP	BD45255	UF	BD45251	V7	BD45252
2.4V	TQ	BD45245	UG	BD45241	V8	BD45242
2.3V	TR	BD45235	UH	BD45231	V9	BD45232

●**Lineup - continued**

Table 2. CMOS Output Type

Detection Voltage	Counter Timer Delay Time Settings					
	50ms		100ms		200ms	
	Marking	Part Number	Marking	Part Number	Marking	Part Number
4.8V	VA	BD46485	W2	BD46481	WU	BD46482
4.7V	VB	BD46475	W3	BD46471	WV	BD46472
4.6V	VC	BD46465	W4	BD46461	WW	BD46462
4.5V	VD	BD46455	W5	BD46451	WX	BD46452
4.4V	VE	BD46445	W6	BD46441	WY	BD46442
4.3V	VF	BD46435	W7	BD46431	WZ	BD46432
4.2V	VG	BD46425	W8	BD46421	X0	BD46422
4.1V	VH	BD46415	W9	BD46411	X1	BD46412
4.0V	VJ	BD46405	WA	BD46401	X2	BD46402
3.9V	VK	BD46395	WB	BD46391	X3	BD46392
3.8V	VL	BD46385	WC	BD46381	X4	BD46382
3.7V	VM	BD46375	WD	BD46371	X5	BD46372
3.6V	VN	BD46365	WE	BD46361	X6	BD46362
3.5V	VP	BD46355	WF	BD46351	X7	BD46352
3.4V	VQ	BD46345	WG	BD46341	X8	BD46342
3.3V	VR	BD46335	WH	BD46331	X9	BD46332
3.2V	VS	BD46325	WJ	BD46321	XA	BD46322
3.1V	VT	BD46315	WK	BD46311	XB	BD46312
3.0V	VU	BD46305	WL	BD46301	XC	BD46302
2.9V	VV	BD46295	WM	BD46291	XD	BD46292
2.8V	VW	BD46285	WN	BD46281	XE	BD46282
2.7V	VX	BD46275	WP	BD46271	XF	BD46272
4.8V	VY	BD46265	WQ	BD46261	XG	BD46262
4.7V	VZ	BD46255	WR	BD46251	XH	BD46252
4.6V	W0	BD46245	WS	BD46241	XJ	BD46242
4.5V	W1	BD46235	WT	BD46231	XK	BD46232

● **Absolute maximum ratings**

Parameter		Symbol	Limits	Unit
Power Supply Voltage		V_DD-GND	-0.3 to +10	V
Output Voltage	Nch Open Drain Output	VOUT	GND-0.3 to +10	V
	CMOS Output		GND-0.3 to V_DD+0.3	
Output Current		Io	60	mA
ER pin Voltage		VCT	GND-0.3 to V_DD+0.3	V
Power Dissipation *1 *2		Pd	540	mW
Operating Temperature		Topr	-40 to +105	°C
Ambient Storage Temperature		Tstg	-55 to +125	°C

*1   Reduced by 5.4mW/°C when used over 25°C.
*2   When mounted on ROHM standard circuit board (70mm×70mm×1.6mm, glass epoxy board).

●**Electrical characteristics (Unless Otherwise Specified Ta=-40 to 105°C)**

Parameter	Symbol	Condition		Limit			Unit
				Min.	Typ.	Max.	
Detection Voltage	V_DET	V_DD=H→L, R_L=470kΩ *1		V_DET(T) ×0.99	V_DET(T)	V_DET(T) ×1.01	V
		VDET=2.5V	Ta=+25°C	2.475	2.5	2.525	
			Ta=-40°C to 85°C	2.417	-	2.580	
			Ta=85°C to 105°C	2.422	-	2.598	
		VDET=3.0V	Ta=+25°C	2.970	3.0	3.030	
			Ta=-40°C to 85°C	2.901	-	3.095	
			Ta=85°C to 105°C	2.906	-	3.117	
		VDET=3.3V	Ta=+25°C	3.267	3.3	3.333	
			Ta=-40°C to 85°C	3.191	-	3.405	
			Ta=85°C to 105°C	3.196	-	3.429	
		VDET=4.2V	Ta=+25°C	4.158	4.2	4.242	
			Ta=-40°C to 85°C	4.061	-	4.334	
			Ta=85°C to 105°C	4.068	-	4.364	
		VDET=4.8V	Ta=+25°C	4.752	4.8	4.848	
			Ta=-40°C to 85°C	4.641	-	4.953	
			Ta=85°C to 105°C	4.649	-	4.988	
Detection Voltage Temperature coefficient	V_DET/ΔT	-40°C to +105°C		-	±100	±360	ppm/°C
Hysteresis Voltage	ΔV_DET	V_DD=L→H→L, R_L=470kΩ		V_DET(T) ×0.03	V_DET(T) ×0.05	V_DET(T) ×0.08	V
'High' Output Delay time	tPLH	C_L=100pF, R_L=100kΩ *1, *2, *3	BD45xx5, BD46xx5	45	50	55	ms
			BD45xx1, BD46xx1	90	100	110	
			BD45xx2, BD46xx2	180	200	220	
Circuit Current when ON	I_DD1	V_DD=VDET-0.2V, V_ER=0V VDET=2.3V to 3.1V *1		-	0.70	2.10	µA
		V_DD=VDET-0.2V, V_ER=0V VDET=2.3V to 3.1V		-	0.70	2.85	
		V_DD=VDET-0.2V, V_ER=0V VDET=3.2V to 4.2V *1		-	0.75	2.25	
		V_DD=VDET-0.2V, V_ER=0V VDET=3.2V to 4.2V		-	0.75	3.00	
		V_DD=VDET-0.2V, V_ER=0V VDET=4.3V to 4.8V *1		-	0.80	2.40	
		V_DD=VDET-0.2V, V_ER=0V VDET=4.3V to 4.8V		-	0.80	3.15	
Circuit Current when OFF	I_DD2	V_DD=VDET+0.2V, V_ER=0V VDET=2.3V to 3.1V *1		-	0.75	2.25	µA
		V_DD=VDET+0.2V, V_ER=0V VDET=2.3V to 3.1V		-	0.75	4.28	
		V_DD=VDET+0.2V, V_ER=0V VDET=3.2V to 4.2V *1		-	0.80	2.40	
		V_DD=VDET+0.2V, V_ER=0V VDET=3.2V to 4.2V		-	0.80	4.50	
		V_DD=VDET+0.2V, V_ER=0V VDET=4.3V to 4.8V *1		-	0.85	2.55	
		V_DD=VDET+0.2V, V_ER=0V VDET=4.3V to 4.8V		-	0.85	4.73	

V_DET(T):Standard Detection Voltage (2.3V to 4.8V, 0.1V step)
R_L :Pull-up resistor to be connected between V_OUT and power supply.
C_L :Capacitor to be connected between V_OUT and GND.
*1   Guarantee is Ta=25°C.
*2   tPLH:V_DD=(V_DET(T)-0.5V)→(V_DET(T)+0.5V)
*3   tPLH:V_DD=Please set the rise up time between V_DD=0→V_DET to more than 100µs.
Attention: Please connect the GND when you don't use 'ER'

●**Electrical characteristics (Unless Otherwise Specified Ta=-40 to 105°C) - continued**

Parameter	Symbol	Condition	Limit Min.	Limit Typ.	Limit Max.	Unit
Operating Voltage Range	V$_{OPL}$	V$_{OL}$≤0.4V, R$_L$=470kΩ, Ta=25 to 105°C	0.95	-	-	V
		V$_{OL}$≤0.4V, R$_L$=470kΩ, Ta=-40 to 25°C	1.20	-	-	
'High' Output Voltage (Pch)	V$_{OH}$	VDD=4.8V, I$_{SOURCE}$= 1.0 mA, VDET(2.3V to 4.2V)	VDD-0.5	-	-	V
		VDD=6.0V, I$_{SOURCE}$= 1.2 mA, VDET(4.3V to 4.8V)	VDD-0.5	-	-	
'Low' Output Voltage (Nch)	V$_{OL}$	VDD=1.2V, I$_{SINK}$ = 0.45 mA	-	-	0.3	V
		VDD=2.4V, I$_{SINK}$ = 1.3 mA, VDET(2.7V to 4.8V)	-	-	0.3	
Leak Current when OFF	I$_{leak}$	VDD=VDS=10V *1	-	-	0.1	µA
ER Pin 'H' Voltage	V$_{EH}$	*1	2.0	-	-	V
ER Pin 'L' Voltage	V$_{EL}$	*1	-	-	0.8	V
ER Pin Input Current	I$_{EL}$		-	1	10	µA

V$_{DET}$(T):Standard Detection Voltage (2.3V to 4.8V, 0.1V step)
R$_L$:Pull-up resistor to be connected between V$_{OUT}$ and power supply.
C$_L$:Capacitor to be connected between V$_{OUT}$ and GND.
*1　Guarantee is Ta=25°C.
Attention: Please connect the GND when you don't use 'ER'

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●**Block Diagrams**
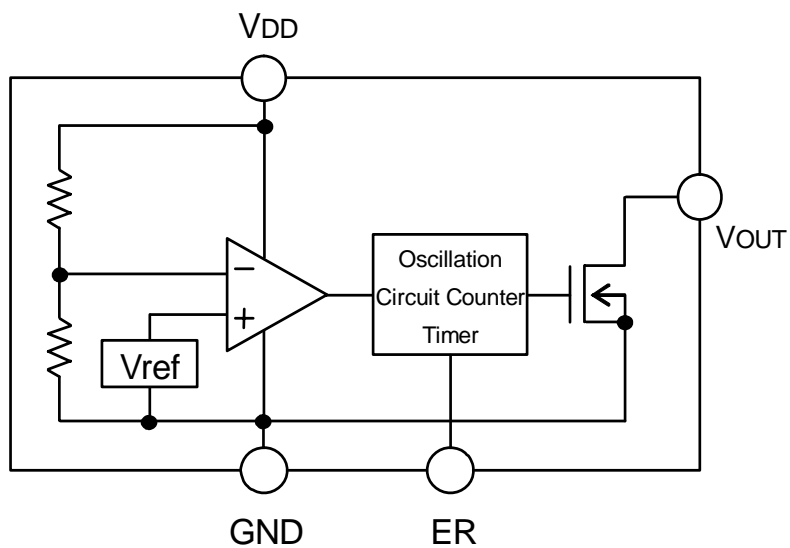
Fig.1 BD45xxx Series

Fig.2 BD46xxx Series

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●**Typical Performance Curves**

Fig.3 Circuit Current

Fig.4 "Low" Output Current

Fig.5 "High" Output Current
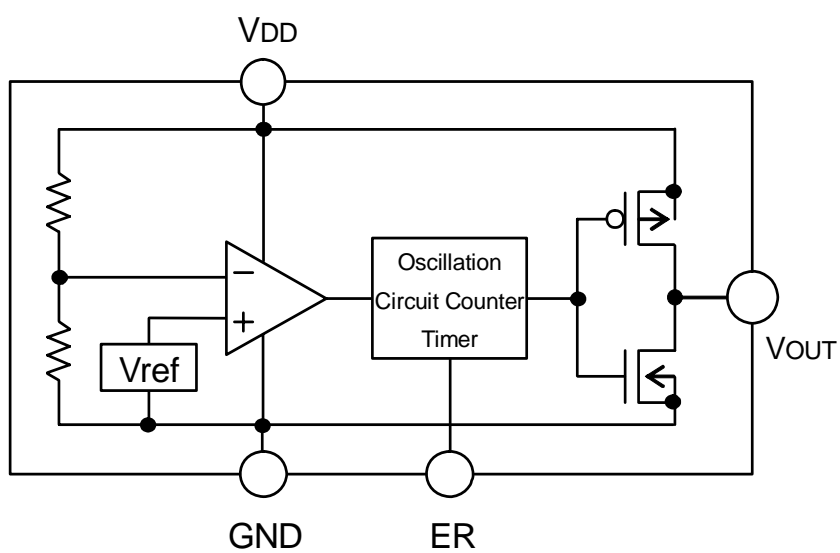
Fig.6 I/O Characteristics
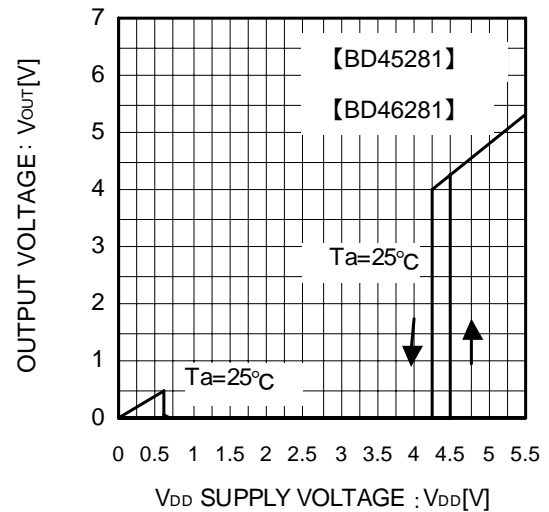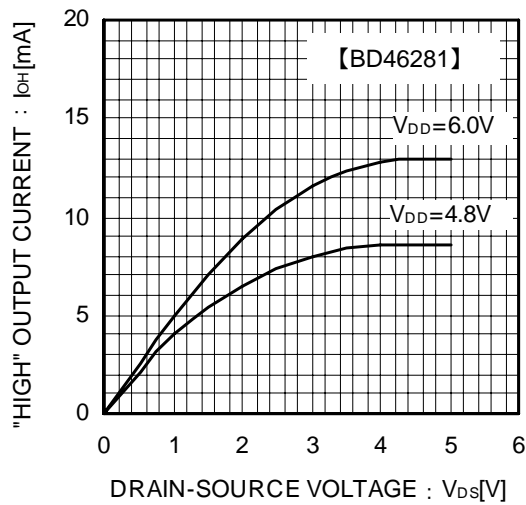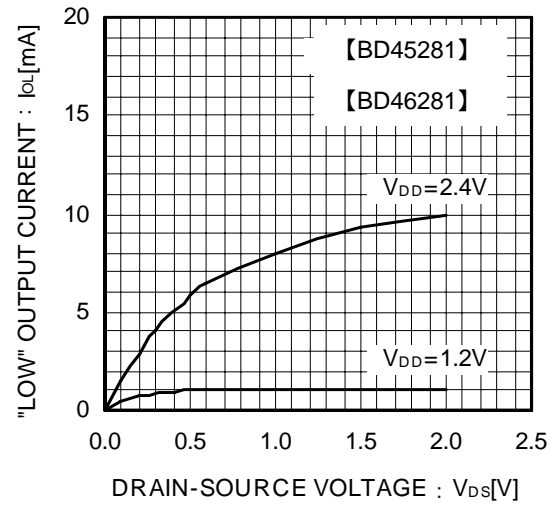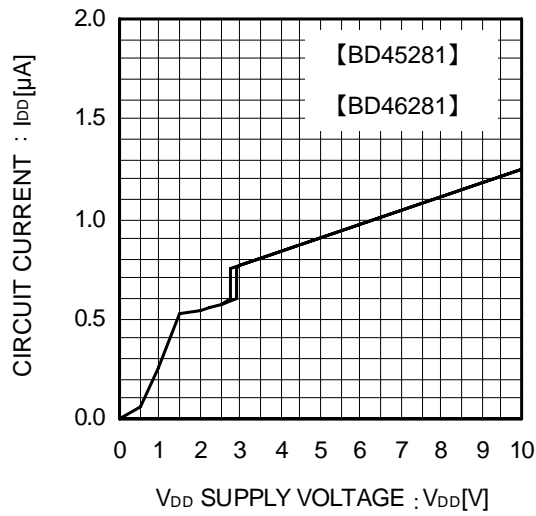
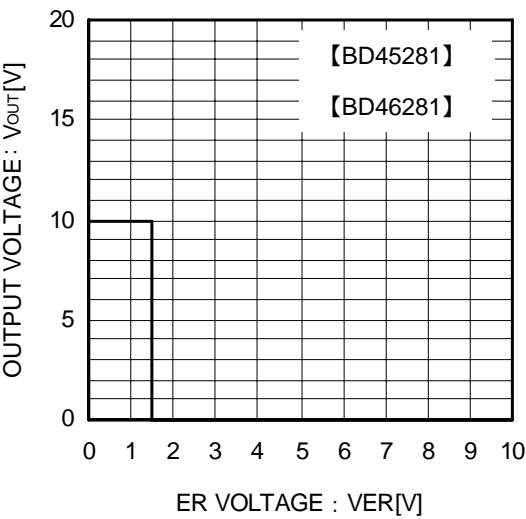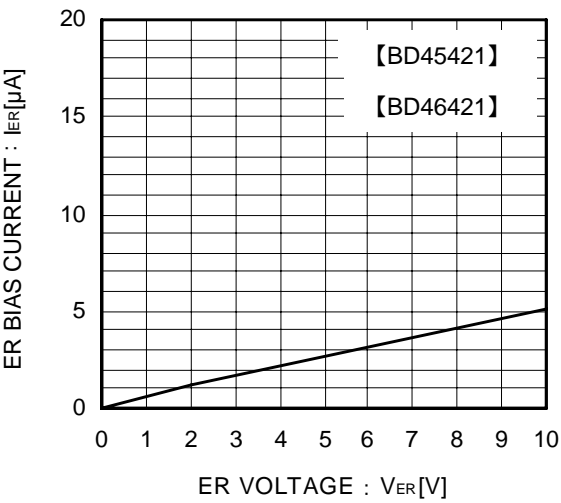●**Typical Performance Curves – continued**

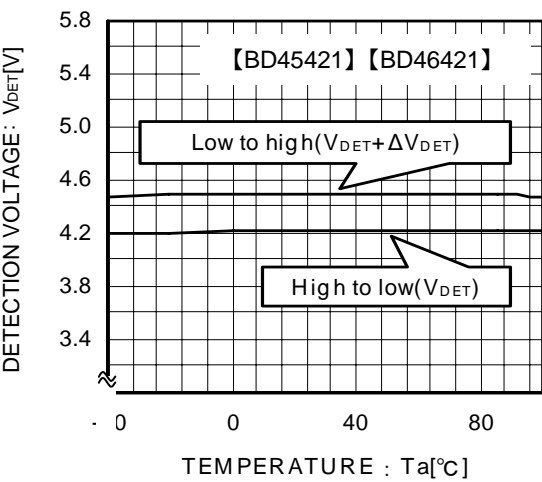Fig.7 ER Terminal Threshold Voltage

Fig.8 ER Terminal Input Current

Fig.9 Detection Voltage
Release Voltage
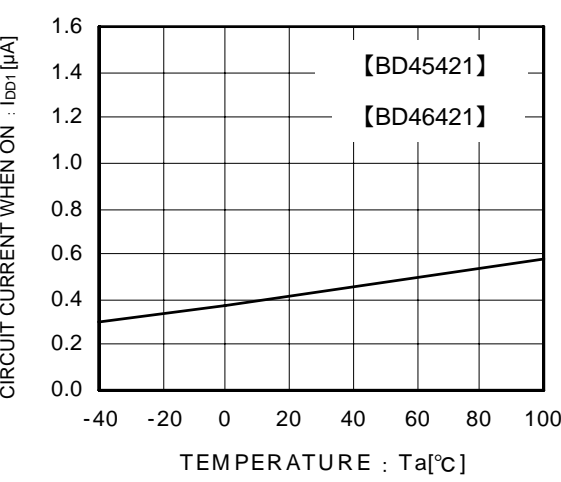
Fig.10 Circuit Current when ON
(V_{DET}-0.2V)

● **Typical Performance Curves – continued**
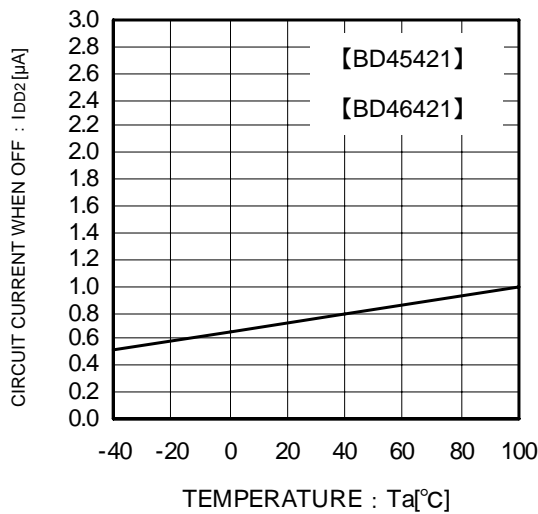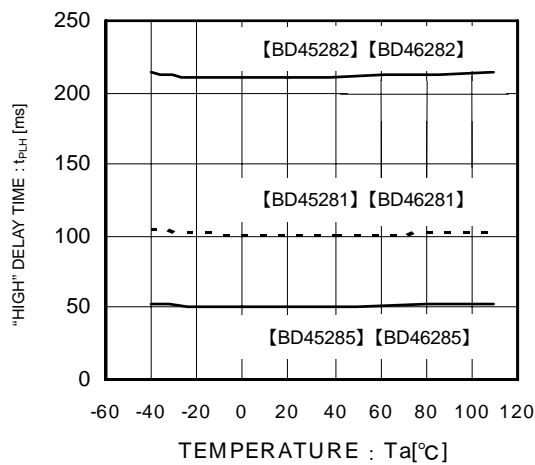

Fig.11 Circuit Current when OFF
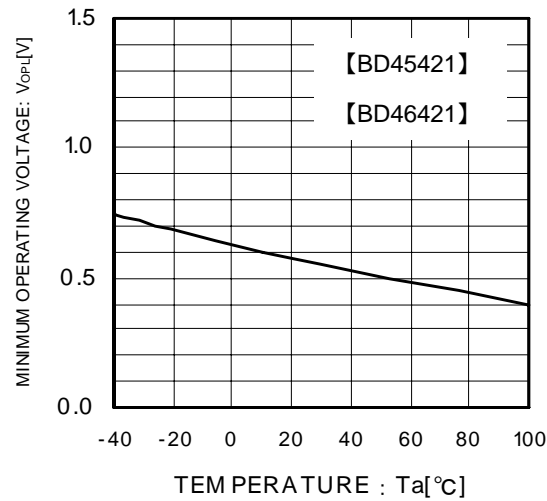
Fig.12 Operating Limit Voltage

Fig.13 Output Delay Time
"Low"→"High"
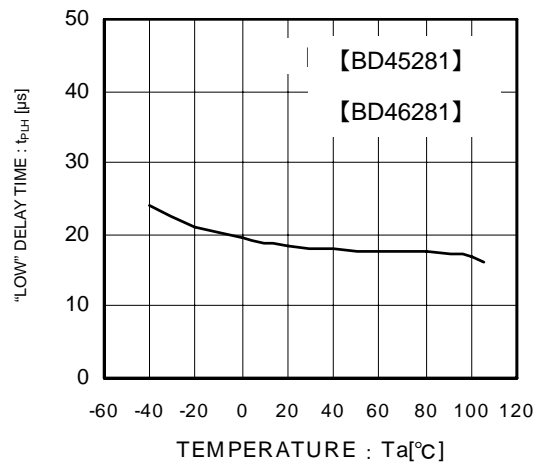
Fig.14 Output Delay Time
"High"→"Low"

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●**Application Information**

Explanation of Operation

For both the open drain type (Fig.15) and the CMOS output type (Fig.16), the detection and release voltages are used as threshold voltages. When the voltage applied to the V_{DD} pins reaches the applicable threshold voltage, the V_{OUT} terminal voltage switches from either "High" to "Low" or from "Low" to "High". Because the BD45xxx series uses an open drain output type, it is necessary to connect either a pull-up resistor to V_{DD} or another power supply if needed [The output "High" voltage (V_{OUT}) in this case becomes V_{DD} or the voltage of the other power supply].
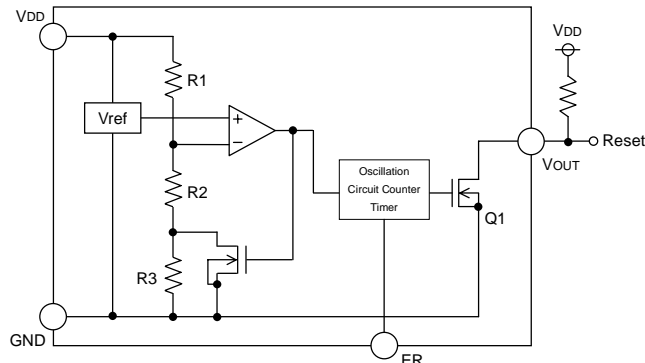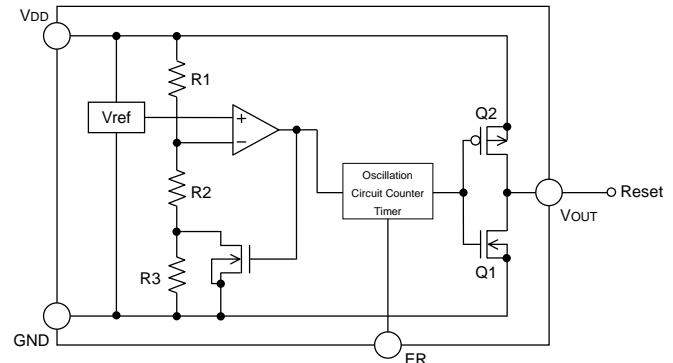
Fig.15 (BD45xxx Type Internal Block Diagram)   Fig.16 (BD46xxx Type Internal Block Diagram)

Reference Data

Examples of Leading (t_{PLH}) and Falling (t_{PHL}) Output

Part Number	t_{PLH}[ms]	t_{PHL}[μs]
BD45275G	50	18
BD46275G	50	18

V_{DD}=2.2V→3.2V V_{DD}=3.2V→2.2V

*This data is for reference only.

The figures will vary with the application, so please confirm actual operating conditions before use.

Timing Waveform

Example: The following shows the relationship between the input voltages V_{DD}, the output voltage V_{OUT} and ER terminal when the input power supply voltage V_{DD} is made to sweep up and sweep down (the circuits are those in Fig. 12 and 13).
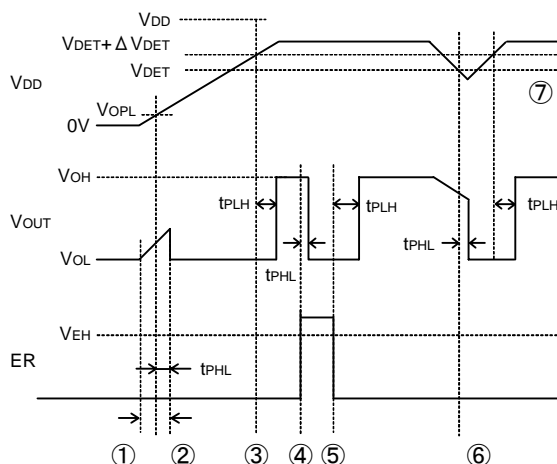
Fig.17 Timing Waveform

① When the power supply is turned on, the output is unstable from after over the operating limit voltage (V_{OPL}) until t_{PHL}. Therefore it is possible that the reset signal is not outputted when the rise time of V_{DD} is faster than t_{PHL}.

② When V_{DD} is greater than V_{OPL} but less than the reset release voltage ($V_{DET} + \Delta V_{DET}$), the output voltages will switch to Low.

③ If V_{DD} exceeds the reset release voltage ($V_{DET} + \Delta V_{DET}$), the counter timer start and V_{OUT} switches from L to H.

④ When more than the high level voltage is supplied to the ER terminal, V_{OUT} comes to "L" after t_{PLH} delay time. Therefore, a time when ER terminal is "H" is necessary for 100μsec or more.

⑤ When the ER terminal switches to Low, the counter timer starts to operate, a delay of t_{PLH} occurs, and V_{OUT} switches from "L" to "H".

⑥ If V_{DD} drops below the detection voltage (V_{DET}) when the power supply is powered down or when there is a power supply fluctuation, V_{OUT} switches to L (with a delay of t_{PHL}).

⑦ The potential difference between the detection voltage and the release voltage is known as the hysteresis width (ΔV_{DET}). The system is designed such that the output does not toggle with power supply fluctuations within this hysteresis width, preventing malfunctions due to noise.

These time changes by the application and use it, please verify and confirm using practical applications.

●**Circuit Applications**

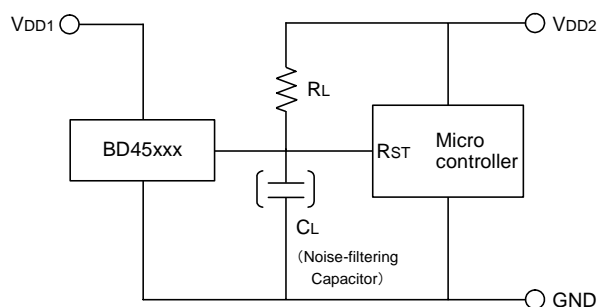1) Examples of common power supply detection reset circuits.
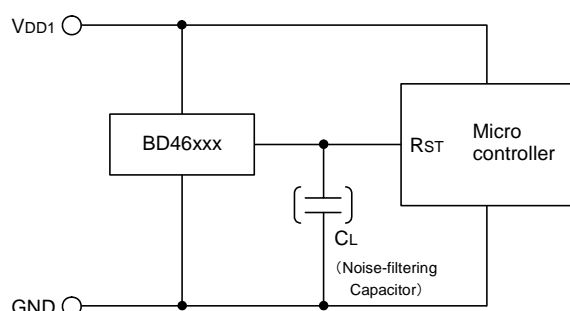

Fig.18 Open Drain Output Type

Fig.19 CMOS Output Type

Application examples of BD45xxx series (Open Drain output type) and BD46xxx series (CMOS output type) are shown below.

CASE1: Power supply of the microcontroller (V_{DD2}) differs from the power supply of the reset detection (V_{DD1}).
Use an open drain output type (BD45xxx) with a load resistance R_L as shown Fig.18.

CASE2: Power supply of the microcontroller (V_{DD1}) is same as the power supply of the reset detection (V_{DD1}).
Use a CMOS output type (BD46xxx) device or an open drain output type (BD45xxx) device with a pull up resistor between the output and V_{DD1}.

When a capacitance C_L for noise filtering is connected to the V_{OUT} pin (the reset signal input terminal of the microcontroller), please take into account the waveform of the rise and fall of the output voltage (V_{OUT}).

2) The following is an example of a circuit application in which an OR connection between two types of detection voltage resets the microcontroller.
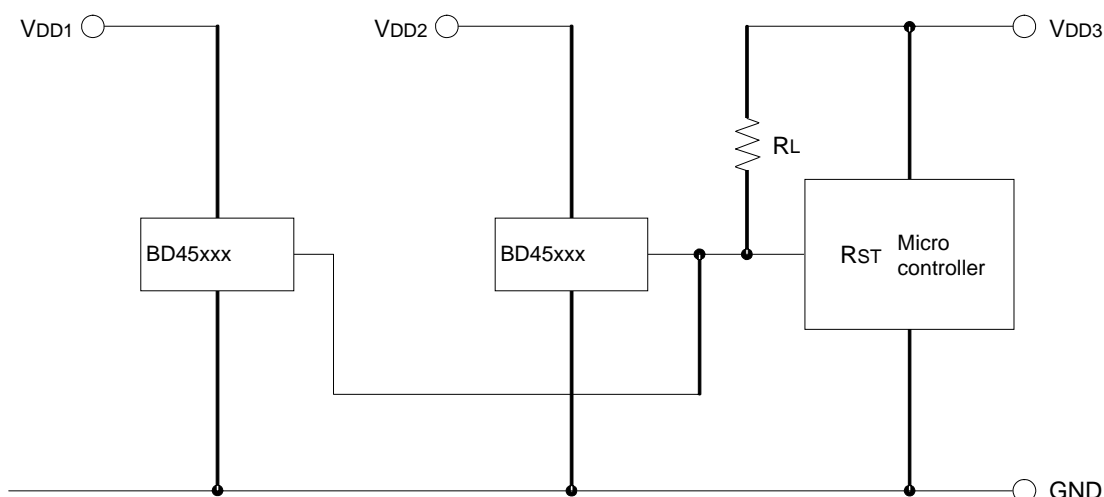

Fig. 20

To reset the microcontroller when many independent power supplies are used in the system, OR connect an open drain output type (BD45xxx series) to the microcontroller's input with pull-up resistor to the supply voltage of the microcontroller (V_{DD3}) as shown in Fig. 20. By pulling-up to V_{DD3}, output "High" voltage of micro-controller power supply is possible.

3) Examples of the power supply with resistor dividers.

In applications wherein the power supply voltage of an IC comes from a resistor divider circuit, an in-rush current will flow into the circuit when the output level switches from "High" to "Low" or vice versa. In-rush current is a sudden surge of current that flows from the power supply (VDD) to ground (GND) as the output logic changes its state. This current flow may cause malfunction in the systems operation such as output oscillations, etc.
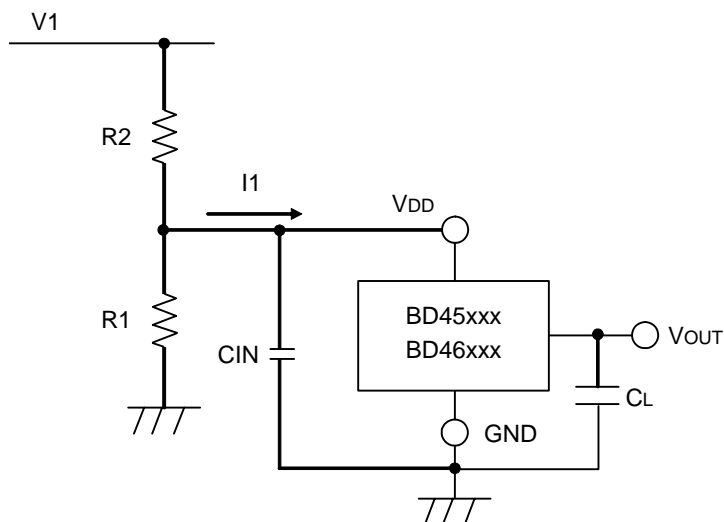

Fig. 21

When an in-rush current (I1) flows into the circuit (Refer to Fig. 21) at the time when output switches from "Low" to "High", a voltage drop of I1×R2 (input resistor) will occur in the circuit causing the VDD supply voltage to decrease. When the VDD voltage drops below the detection voltage, the output will switch from "High" to "Low". While the output voltage is at "Low" condition, in-rush current will stop flowing and the voltage drop will be reduced. As a result, the output voltage will switches again from "Low" to "High" which causes an in-rush current and a voltage drop. This operation repeats and will result to oscillation.
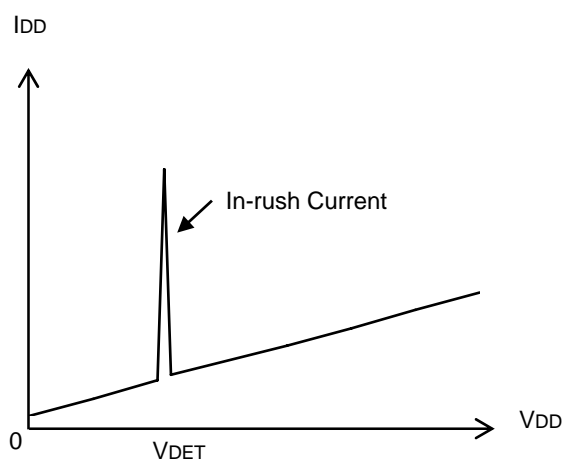

Fig. 22 Current Consumption vs. Power Supply Voltage

●**Operational Notes**

1) Absolute maximum ratings
    Operating the IC over the absolute maximum ratings may damage the IC. The damage can either be a short circuit between pins or an open circuit between pins. Therefore, it is important to consider circuit protection measures, such as adding a fuse, in case the IC is operated over the absolute maximum ratings.

2) Ground Voltage
    The voltage of the ground pin must be the lowest voltage of all pins of the IC at all operating conditions. Ensure that no pins are at a voltage below the ground pin at any time, even during transient condition.

3) Recommended operating conditions
    These conditions represent a range within which the expected characteristics of the IC can be approximately obtained. The electrical characteristics are guaranteed under the conditions of each parameter.

4) Bypass Capacitor for Noise Rejection
    To help reject noise, put a 1μF capacitor between V_{DD} pin and GND and 1000pF capacitor between V_{OUT} pin and GND. Be careful when using extremely big capacitor as transient response will be affected.

5) Short between pins and mounting errors
    Be careful when mounting the IC on printed circuit boards. The IC may be damaged if it is mounted in a wrong orientation or if pins are shorted together. Short circuit may be caused by conductive particles caught between the pins.

6) Operation under strong electromagnetic field
    Operating the IC in the presence of a strong electromagnetic field may cause the IC to malfunction.

7) The V_{DD} line impedance might cause oscillation because of the detection current.

8) A V_{DD} to GND capacitor (as close connection as possible) should be used in high V_{DD} line impedance condition.

9) Lower than the mininum input voltage puts the V_{OUT} in high impedance state, and it must be V_{DD} in pull up (V_{DD}) condition.

10) This IC has extremely high impedance terminals. Small leak current due to the uncleanness of PCB surface might cause unexpected operations. Application values in these conditions should be selected carefully. If the leakage of about 1MΩ is assumed between the ER terminal and the GND terminal, 100kΩ connection between the ER terminal and the V_{DD} terminal would be recommended. If the leakage is assumed between the V_{OUT} terminal and the GND terminal, the pull-up resistor should be less than 1/10 of the assumed leak resistance.

11) External parameters
    The recommended parameter range for R_L is 50kΩ to 1MΩ. There are many factors (board layout, etc) that can affect characteristics. Please verify and confirm using practical applications.

12) Power on reset operation
    Please note that the power on reset output varies with the V_{DD} rise time. Please verify the behavior in the actual operation.

13) Testing on application boards
    When testing the IC on an application board, connecting a capacitor directly to a low-impedance output pin may subject the IC to stress. Always discharge capacitors completely after each process or step. The IC's power supply should always be turned off completely before connecting or removing it from the test setup during the inspection process. To prevent damage from static discharge, ground the IC during assembly and use similar precautions during transport and storage.

14) Rush current
    When power is first supplied to the IC, rush current may flow instantaneously. It is possible that the charge current to the parasitic capacitance of internal photo diode or the internal logic may be unstable. Therefore, give special consideration to power coupling capacitance, power wiring, width of GND wiring, and routing of connections.

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   [b] Use of our Products outdoors or in places where the Products are exposed to direct sunlight or dust
   [c] Use of our Products in places where the Products are exposed to sea wind or corrosive gases, including Cl_2, H_2S, NH_3, SO_2, and NO_2
   [d] Use of our Products in places where the Products are exposed to static electricity or electromagnetic waves
   [e] Use of our Products in proximity to heat-producing components, plastic cords, or other flammable items
   [f] Sealing or coating our Products with resin or other coating materials
   [g] Use of our Products without cleaning residue of flux (even if you use no-clean type fluxes, cleaning residue of flux is recommended); or Washing our Products by using water or water-soluble cleaning agents for cleaning residue after soldering
   [h] Use of the Products in places subject to dew condensation

4) The Products are not subject to radiation-proof design.

5) Please verify and confirm characteristics of the final or mounted products in using the Products.

6) In particular, if a transient load (a large amount of load applied in a short period of time, such as pulse) is applied, confirmation of performance characteristics after on-board mounting is strongly recommended. Avoid applying power exceeding normal rated power; exceeding the power rating under steady-state loading condition may negatively affect product performance and reliability.

7) De-rate Power Dissipation (Pd) depending on Ambient temperature (Ta). When used in sealed area, confirm the actual ambient temperature.

8) Confirm that operation temperature is within the specified range described in the product specification.

9) ROHM shall not be in any way responsible or liable for failure induced under deviant condition from what is defined in this document.

●Precaution for Mounting / Circuit board design

1) When a highly active halogenous (chlorine, bromine, etc.) flux is used, the residue of flux may negatively affect product performance and reliability.

2) In principle, the reflow soldering method must be used; if flow soldering method is preferred, please consult with the ROHM representative in advance.

For details, please refer to ROHM Mounting specification

●Precautions Regarding Application Examples and External Circuits

1) If change is made to the constant of an external circuit, please allow a sufficient margin considering variations of the characteristics of the Products and external components, including transient characteristics, as well as static characteristics.

2) You agree that application notes, reference designs, and associated data and information contained in this document are presented only as guidance for Products use. Therefore, in case you use such information, you are solely responsible for it and you must exercise your own independent verification and judgment in the use of such information contained in this document.   ROHM shall not be in any way responsible or liable for any damages, expenses or losses incurred by you or third parties arising from the use of such information.

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This Product is electrostatic sensitive product, which may be damaged due to electrostatic discharge. Please take proper caution in your manufacturing process and storage so that voltage exceeding the Products maximum rating will not be applied to Products. Please take special care under dry condition (e.g. Grounding of human body / equipment / solder iron, isolation from charged objects, setting of Ionizer, friction prevention and temperature / humidity control).

●Precaution for Storage / Transportation

1) Product performance and soldered connections may deteriorate if the Products are stored in the places where:
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    [b]   the temperature or humidity exceeds those recommended by ROHM
    [c]   the Products are exposed to direct sunshine or condensation
    [d]   the Products are exposed to high Electrostatic

2) Even under ROHM recommended storage condition, solderability of products out of recommended storage time period may be degraded. It is strongly recommended to confirm solderability before using Products of which storage time is exceeding the recommended storage time period.

3) Store / transport cartons in the correct direction, which is indicated on a carton with a symbol. Otherwise bent leads may occur due to excessive stress applied when dropping of a carton.

4) Use Products within the specified time after opening a humidity barrier bag. Baking is required before using Products of which storage time is exceeding the recommended storage time period.

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